NSN 5962-01-377-2585

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmed
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
D-8 mil-m-38510
Product Name:
116-input 6-output registered and-or gate array
Voltage Rating And Type Per Characteristic:
4.5 volts applied and 5.5 volts applied
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Terminal Type And Quantity:
20 printed circuit
Specification Data:
8134938510/50607bra government specification and 67268-5962-8515507ra government standard
Departure From Cited Designator:
Altered by programming & testing
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
A458a0